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Olga Nazarenko, Martin Kotyrba, Sergii Yakunin, Michael Wörle, Bogdan Benin, et al.. Guanidinium and mixed Cesium-Guanidinium Tin(II) Bromides: Effects of Quantum Confinement and Out-of-Plane Octahedral Tilting. *Chemistry of Materials*, 2019, 31 (6), pp.2121-2129. 10.1021/acs.chemmater.9b00038 . hal-02019936

HAL Id: hal-02019936

<https://hal.science/hal-02019936>

Submitted on 13 Mar 2019

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Guanidinium and mixed Cesium-Guanidinium Tin(II) Bromides: Effects of Quantum Confinement and Out-of-Plane Octahedral Tilting

Olga Nazarenko,^{†,‡} Martin R. Kotyrba,^{†,‡} Sergii Yakunin,^{†,‡} Michael Wörle,[†] Bogdan M. Benin,^{†,‡} Gabriele Rainò,^{†,‡} Frank Krumeich,[†] Mikael Kepenekian,[§] Jacky Even,^{||} Claudine Katan,[§] Maksym V. Kovalenko^{†,‡*}

[†] Laboratory of Inorganic Chemistry, Department of Chemistry and Applied Biosciences, ETH Zürich, Vladimir-Prelog-Weg 1, CH-8093 Zürich, Switzerland

[§] Univ Rennes, ENSCR, INSA Rennes, CNRS, ISCR (Institut des Sciences Chimiques de Rennes) - UMR 6226, F-35000 Rennes, France

^{||} Univ Rennes, INSA Rennes, CNRS, Institut FOTON - UMR 6082, F-35000 Rennes, France

[‡] Laboratory for Thin Films and Photovoltaics, Empa – Swiss Federal Laboratories for Materials Science and Technology, Überlandstrasse 129, CH-8600 Dübendorf, Switzerland

ABSTRACT: Hybrid organic-inorganic main-group metal halide compounds are the subject of intense research owing to their unique optoelectronic characteristics. In this work, we report on the synthesis, the structure, and the electronic and optical properties of a family of hybrid tin (II) bromide compounds comprising guanidinium [G, C(NH₂)₃⁺] and mixed cesium-guanidinium cations: G₂SnBr₄, CsGSnBr₄, and Cs₂GSn₂Br₇. G₂SnBr₄ has a one-dimensional structure that consists of chains of corner-sharing [SnBr₅]²⁻ square pyramids and G cations situated in-between the chains. Cs⁺ exhibits a pronounced structure-directing effect where a mixture of Cs⁺ and G cations forms mono- and bi-layered two-dimensional perovskites: CsGSnBr₄ and Cs₂GSn₂Br₇. Furthermore, the flat shapes of the guanidinium cations induce anisotropic out-of-plane tilts of the [SnBr₆]⁴⁻ octahedra in the CsGSnBr₄ and Cs₂GSn₂Br₇ compounds. In G₂SnBr₄, the Sn lone pair is highly stereoactive and favors non-octahedral, *i.e.*, square pyramidal coordination of Sn(II). G₂SnBr₄ exhibits bright broadband emission from self-trapped excitonic states, owing to its soft lattice and electronic localization. This emission in G₂SnBr₄ is characterized by a PL QY of 2 % at room temperature (RT; 75±5 % at 77 K) and a fast PL lifetime of 18 ns at RT.

Hybrid organic-inorganic tin (II) halide compounds are intensely researched as to their photophysics and electronic properties, which are all governed by the structural diversity of Sn(II)-halide anionic networks.¹⁻⁶ Such compounds are promising for application in light-emitting devices,⁶⁻⁸ solar cells⁹⁻¹⁰ and photodetectors.¹¹ The crystal structure of hybrid tin (II) halide compounds consists of Sn(II)-X (X = Cl, Br, I) coordination anionic networks and organic cations. Sn(II)-X units can arrange themselves into a vast variety of structures: from extended three-dimensional (3D) structures composed of

Sn(II)-X coordination polyhedra connected by corners, edges and faces to isolated polyhedral units (0D-compounds) with a plethora of structures in-between.^{1, 3, 12-16} The Sn(II)-X units thus far observed experimentally include trigonal pyramids (coordination number, CN, of 3),¹⁷⁻¹⁸ seesaws (CN = 4),⁶ square pyramids (CN = 5),^{5, 19} and, most commonly, octahedral units (CN = 6).^{1, 20} The coordination geometry of the Sn(II) ion is a complex interplay that involves the effects of the stereoactivity of the 5s-lone pair as well as the geometry of the organic cation and the interactions of the cation with inorganic units such as hydrogen bonding. Satisfactory rationalization (and prediction) of these effects on the atomistic and electronic structure of the resulting compounds remains a formidable challenge.

The electronic band structure of hybrid Sn(II) halide compounds at the band gap is formed mainly by Sn 5*p* and 5*s* orbitals, and halide *np* orbitals. Non-conjugated organic amines do not significantly contribute to frontier orbitals.²¹⁻²² In hybrid tin (II) halide perovskite structures, such as (C₆H₅CH₂CH₂NH₃)₂SnI₄, the *ns*² pair of Sn defines an antibonding character of the valence band maximum by coupling with the *p* orbitals of halogen atoms.²² The bandgap depends on the dimensionality and connectivity of the Sn(II)-X units, the atomic number of the halogen, and distortions of the metal-halide polyhedra (governed by the organic moiety).^{1, 23-24} For instance, the optical bandgap of the 3D CH₃NH₃SnI₃ is 1.26 eV, whereas the 2D [C₆H₅(CH₂)₂NH₃]₂SnI₄ has an optical absorption edge at 1.97 eV.²⁵

In the context of real-world applications, low-dimensional hybrid Sn(II) halides might eventually be of use as bright light emitters for lighting and other applications. For instance, 0D (C₄N₂H₁₄Br)₄SnBr₃I₃ [organic cation is N,N'-dimethylethylene-1,2-diammonium] demonstrates bright, yellow, broad-band photoluminescence (PL) with a quantum yield (QY) of ~85 % and a large Stokes shift (>100 nm) and a full width of half

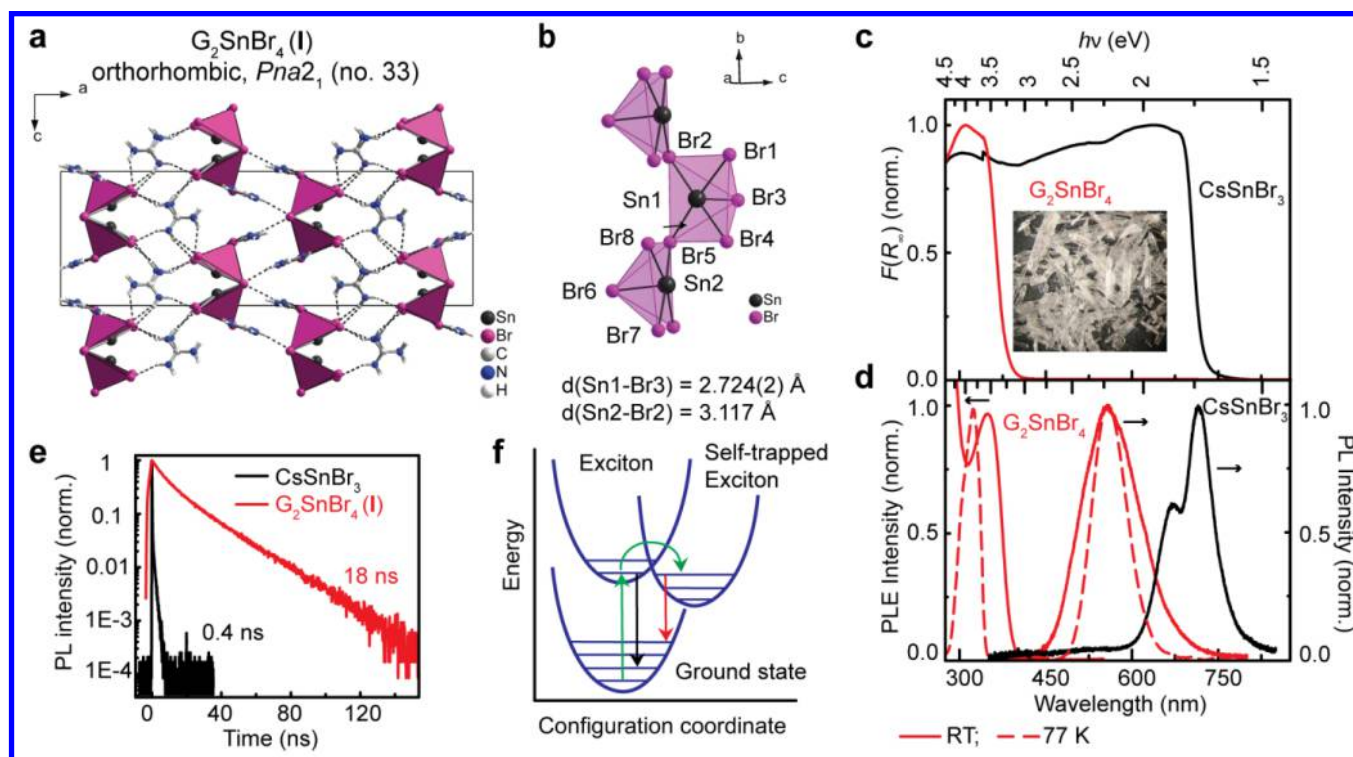


Figure 1. (a, b) Crystal structure of guanidinium tin bromide - G_2SnBr_4 (I). (c) Kubelka-Munk function $F(R_\infty) = (1-R_\infty)^2/2R_\infty$ (R_∞ - diffuse reflectance) of $CsSnBr_3$ and I. (d) Photoluminescence (PL) and PL excitation (PLE) spectra measured on powdered crystals of $CsSnBr_3$ and G_2SnBr_4 (I). (e) Time resolved PL traces of $CsSnBr_3$ and I at room temperature (RT). (f) A schematic of the formation of self-trapped excitons.

maximum (FWHM) - 126 nm.⁷ The corresponding compound, $(C_4N_2H_{14}Br)_4SnBr_6$, containing exclusively bromide, exhibits a QY close to 100%.⁸ The structure of these compounds comprises SnX_6^{4-} octahedra isolated by organic cations. Such emission characteristics are attributed to the emission from so-called self-trapped excitons, which are characterized by high binding energies and a low probability of interaction with intrinsic defects.²⁶ Self-trapped excitons form due to a combination of electronic localization of an electron-hole pair (exciton) and structural distortion that occurs fast upon photoexcitation (Figure 1f), which lead to a Jahn-Teller-like distortion in the excited state.²⁷ Hybrid 0D main-group metal halides are characterized by a soft lattice, strongly favoring the formation of self-trapped excitons due to facile structural distortion (exciton-phonon coupling). Radiative relaxation of self-trapped excitons leads to broad-band emission with a large Stokes shift as reported recently for a wide range of Sn(II) and Sb(III) halides.^{3, 6-8, 28-29} In comparison, the emission from 3D $CH_3NH_3SnI_3$ results from free-excitonic states and the PL band is characterized by a small Stokes shift, a narrow full-width at half-maximum (FWHM), and a fast radiative lifetime.^{12, 30}

Both organic and inorganic constituents determine the resulting crystal structure. Thus, organic cations such as formamidinium $[CH(NH_2)^+]$, FA) facilitate the formation of the 3D perovskite network of $FASnI_3$.¹² However, the use of large cations, such as phenethylammonium $[C_6H_5(CH_2)_2NH_3^+]$, typically results in a layered structure.²² A cation that is only slightly larger than FA - guanidinium - forms a layered G_2SnI_4 perovskite crystal structure with corrugated Sn-I layers.³¹ Guanidinium is a highly symmetric molecule (D_{3h}) and a potential contributor of six hydrogen bonds. The G cation, due to its larger-than-FA ionic radius, destabilizes the 3D perovskite network of corner-shared Sn-X octahedra.³²

Instead, G_2SnI_3 forms a 3D network composed of Sn-I octahedra with mixed connectivity: corner- and face-sharing.¹ The appealing attributes of the G-cation are its high thermodynamic stability, strong hydrogen bonding capabilities, and high basicity with $pK_a = 13.6$ due to resonance stabilization by 6-8 kcal/mol.³³⁻³⁴ In a G-Sn-Cl system, there are two known compounds: 1D G_2SnCl_4 and the 3D perovskite-like G_2SnCl_3 .³⁵⁻³⁶ Unlike G_2SnI_4 , where the building blocks are Sn-I octahedra, G_2SnCl_4 has square pyramidal Sn(II) surrounded by Cl ions. So far, no compounds were reported in the G-Sn-Br system.

Herein, we investigated the G-Sn-Br and the mixed-cation Cs-G-Sn-X (X = Br, I) systems, wherein the effect of the additional smaller cation on the obtained structure can be probed. In our study we did not succeed in obtaining quaternary mixed Cs-G-Sn(II) iodides, observing instead known ternary G_2SnI_4 ,³¹ and $CsSnI_3$ phases.³⁷ Therefore, the focus has been on the bromide systems. We have synthesized G_2SnBr_4 (I) (Figure 1a) and compared it to $CsSnBr_3$, and subsequently explored mixed Cs/G phases. G_2SnBr_4 is a 1D, luminescent compound with broadband PL and a PLQY of 2% at RT. It is thermally stable up to 300 °C. Two layered perovskite compounds CsG_2SnBr_4 (II) and $Cs_2G_2Sn_2Br_7$ (III) were obtained and characterized in terms of their crystal structure, electronic structure, and optical properties. They reveal significant quantum confinement and that the planar shape of the G cation induces significant structural and electronic anisotropy. We then compare these structural effects to those in homologous lead-based compounds.

METHODS

Chemicals, reagents and synthetic procedures. Guanidinium carbonate (G_2CO_3 , 99+ %), hydrobromic acid (HBr, 48 % water solution), Sn powder (99.8 %, ~325 mesh) were purchased from Acros.

Cesium bromide (CsBr, 99 %), hydroiodic acid (HI, 57% water solution stabilized with 1.5 % hypophosphorous acid, H₃PO₂) was obtained from ABCR. Tin(II) bromide (SnBr₂, 99.2 %) was obtained from Alfa Aesar. All chemicals were used as received without further purification.

All syntheses and further manipulations with the products were performed under inert conditions (argon or nitrogen atmosphere) using Schlenk technique. Temperatures of the syntheses, stated below, correspond to the temperatures of the glycerol bath used as a source of heat. The syntheses were conducted in 10-20 ml Schlenk vessels equipped with a stirring bar.

G₂SnBr₄ (I) was crystallized from HBr. Briefly, 0.250 g (2.1 mmol) of Sn powder was dissolved in 3 ml of HBr (degassed under stirring in Ar atmosphere for ~20 min beforehand); this mixture was stirred for 10 min at RT and then heated in the glycerol bath at 85-90 °C. When all Sn dissolved, 0.378 g (2.1 mmol) of G₂CO₃ were slowly added. A strong evolution of gas was observed (CO₂). The reaction mixture was then stirred for an additional 5 minutes resulting in a clear colorless solution, whereupon the stirring and the heating were discontinued. Colorless transparent needles crystallized upon cooling and were separated by vacuum filtration under Ar flow. The product was dried under vacuum at 65-70 °C for 6 h. Yield - 41 % (with regard to the initial [Sn]).

CsSnBr₃ was synthesized from stoichiometric quantities of Sn and CsBr precursors in HBr. Briefly, 0.180 g (1.5 mmol) of Sn were dissolved in 3-ml of HBr as described above. Next, 0.320 g (1.5 mmol) CsBr was added, and a black precipitate formed immediately. A mixture was stirred for an additional 5 min at 105 °C. Further manipulations with the product were identical to those with G₂SnBr₄.

Cs₂GSn₂Br₇ (III). 0.107 g (0.9 mmol) of Sn powder was dissolved in 3 ml of HBr, stirred for 10 min at RT and then heated to 85-90 °C. When all Sn dissolved, 0.486 g (2.7 mmol) of G₂CO₃ and 0.1915 g (0.9 mmol) of CsBr were slowly added. A strong evolution of gas (CO₂) was observed and a black precipitate formed. The reaction mixture was stirred and kept at 85-90 °C for about 5 minutes until a slightly yellowish solution resulted. Next, the stirring and heating were discontinued, and the mixture was cooled down under a stream of cold tap-water. Initially, some black precipitate of CsSnBr₃ crystallized out (Figure S1). In a few minutes, red crystals started appearing and the black powder re-dissolved. The mixture was left for one week for further crystallization. Finally, the red product was separated by vacuum filtration under an inert atmosphere and dried under vacuum at 65-70 °C for 6 h.

Cs₈Sn₆Br₁₃I₇ was crystallized from a solution of hot HI and HBr acids under N₂. CsBr (0.500 g, 2.350 mmol) was first dissolved in HBr (4.0 mL) and HI (1.0 mL) solution in a 10 mL Schlenk reaction tube and sparged with N₂ while stirring at RT for 30 min. SnBr₂ (0.111 g, 0.399 mmol) was then added and a black precipitate formed. This mixture was then heated with a glycerol bath until an orange solution resulted (110 °C). The stirring and heating were discontinued, and the solution was cooled to RT. Within an hour orange needles crystallized out. The solution was left overnight for further crystallization. The product was separated by vacuum filtration under N₂ and dried overnight under vacuum (70-80 °C). A yield of 50.8% was estimated relative to initial [Sn].

Characterization. Powder X-ray diffraction (XRD) patterns were collected in transmission mode (Debye-Scherrer-Geometry) with a STADI P diffractometer (STOE & Cie GmbH) equipped with a curved Ge (111)-monochromator (CuKα1 = 1.54056 Å) and a silicon strip MYTHEN 1K Detector (Fa. DECTRIS). For the measurement, a ground powder was placed between an adhesive tape (for CsGSnBr₄ and Cs₂GSn₂Br₇) or sealed in a 0.3 mm glass capillary (for G₂SnBr₄ and CsSnBr₃). **Single-crystal XRD** measurements were conducted on

Bruker Smart Platform diffractometer equipped with an Apex I CCD detector and molybdenum (MoKα = 0.71073 Å) sealed tube as an X-ray source. Crystals were tip-mounted on a micromount with paraffin oil. The data was processed with the APEX3 software package,³⁸ and the structure solution and refinement were performed with SHELXS³⁹ and SHELXL,⁴⁰ respectively, which are embedded in Olex2.⁴¹ The crystal structures were solved with direct methods, light elements (C, N) were located in the difference Fourier map, and hydrogen atoms were placed at calculated positions. The crystallographic data for the reported tin halide compounds were deposited at the Cambridge Crystallographic Data Centre (CCDC) under the codes 1854819 (G₂SnBr₄), 1854833 (Cs₂GSn₂Br₇), 1854838 (CsGSnBr₄), as well as at the Inorganic Crystal Structure Database (ICSD), *i.e.*, card number 434800 for Cs₈Sn₆Br₁₃I₇. **UV-Vis diffuse reflectance spectra** of the microcrystalline powders were collected using a Jasco V670 spectrophotometer equipped with deuterium (D₂) lamp (190 – 350 nm) for use in UV and halogen lamp (330 – 2700 nm) for use in UV/NIR, and an integrating sphere detector (ILN-725) with a working wavelength range of 220 – 2200 nm. The diffuse reflectance data were transformed with Kubelka-Munk model into the absorption/scattering ratio spectrum. **Photoluminescence spectra** were measured with a CCD fiber spectrometer (LR1, Aseq Instruments) with a 355 nm excitation source (frequency-tripled, picosecond Nd:YAG laser, Duetto from Time-Bandwidth). PL emission from the samples passed through a long-pass optical filter with an edge at 400 nm in order to reject the excitation laser line. PL spectra were corrected to the spectral sensitivity of the detection system. For **temperature-dependent PL** measurements, a sample of CsSnBr₃ was placed atop of a 4-stage Peltier cooling/heating element in an evacuated chamber with a quartz window. The sample temperature was adjusted and stabilized with an accuracy of 0.25 °C by a home-made electronic scheme based on an Arduino microcontroller and thermocouple sensor. The current through the Peltier was reversible, thus the setup provided a wide working temperature range of -40 – 120 °C. This is an open-source project by the authors, deposited and described in details at <https://www.researchgate.net/project/High-power-thermoelectric-cooler-TEC-controller-with-4-stage-Peltier-refrigerator-heater>. **Time-resolved photoluminescence (TR-PL)** measurements were performed using a time-correlated single photon counting (TCSPC) setup, equipped with an SPC-130-EM counting module (Becker & Hickl GmbH) and an IDQ-ID-100-20-ULN avalanche photodiode (Quantique) for recording the decay traces. The average radiative lifetimes were determined as: $\tau_{avg} = \frac{\sum_{i=1}^n \tau_i^2 A_i}{\sum_{i=1}^n \tau_i A_i}$, where A_i and τ_i are the corresponding amplitudes and exponential decay parameters in the biexponential analysis. For measurements of PL and PLE spectra at low temperature (77 K), the sample was encapsulated in a quartz tube filled with Ar gas and placed in a homemade cryostat. Low temperature (77 K) and RT absolute PLQY were measured with excitation at 340 nm using Quantaurus-QY spectrometer from Hamamatsu. The sample was encapsulated in a quartz tube filled with Ar gas. PL measurements at lower temperatures (in the case of Cs₂GSn₂Br₇), down to 5 K, were conducted in a helium cryostat and PL spectroscopy was performed by exciting the sample with a frequency-doubled Ti:Sapphire mode-locked laser delivering pulses of about 150 fs duration at 400 nm and a repetition rate of 80 MHz. The time-integrated PL was analyzed using a CCD-coupled grating spectrometer, whereas TR-PL traces were recorded with a streak camera. **Thermal analysis** [thermogravimetry (TG) and differential scanning calorimetry (DSC)] was performed using a Netzsch Simultaneous Thermal Analyzer (STA 449 F5 Jupiter). A powdered sample of G₂SnBr₄ (21.9 mg) was placed in an alumina crucible (without a lid) and heated under Ar gas flow (50 ml/min) to 850 °C (10 °C min⁻¹). **Scanning electron microscopy (SEM)** was carried out on a Quanta 200F microscope (Thermo Fisher Scientific) operated at an acceleration voltage of 20 kV.

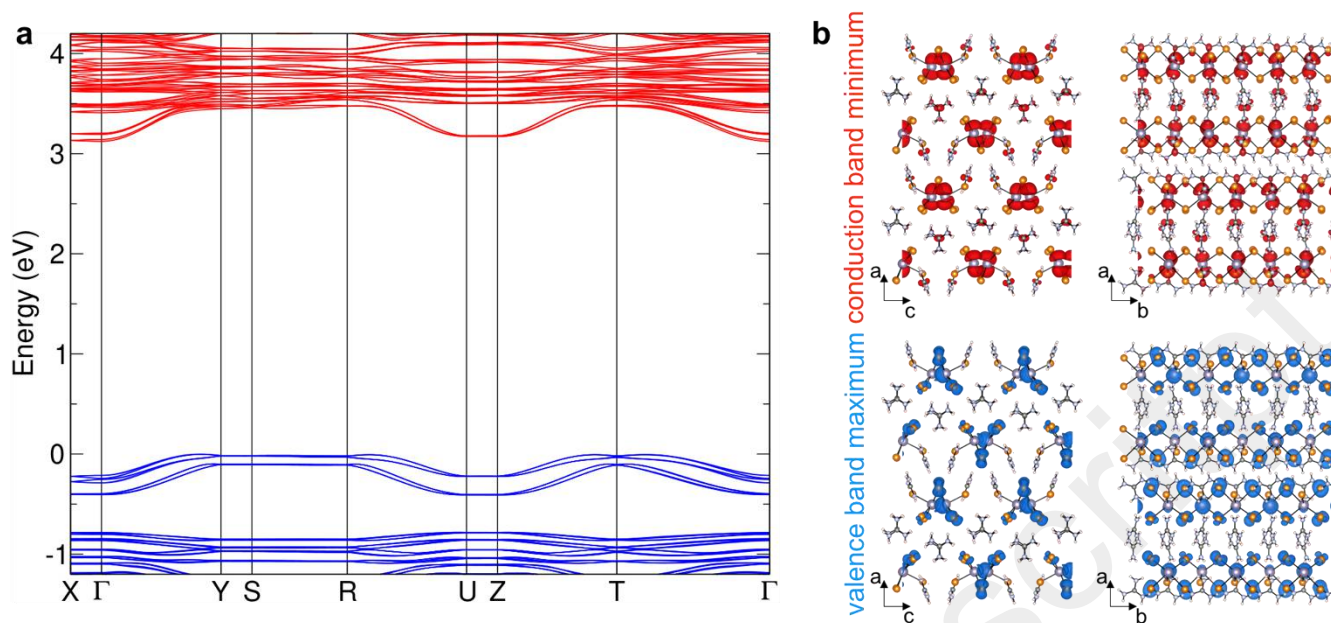


Figure 2. (a) Electronic band diagram of G_2SnBr_4 (**I**) computed by DFT. No dispersion can be observed except in the direction of the 1D chains [010] ($\Gamma \rightarrow Y$, $R \rightarrow U$, and $Z \rightarrow T$ paths). The space group $Pna2_1$ is a polar space group. Therefore, a Rashba splitting of the band edge states is predicted both in the conduction and valence bands away from the Y, R and T critical points of the Brillouin zone. (b) Representation of the electronic densities of the conduction (red) and valence (blue) edge states.

Energy-dispersive X-ray spectroscopy (EDXS) was performed with an Octane SDD detector (EDAX, Ametec) attached to the microscope column. For spectra recording and quantification (ZAF correction), the software Gemini (EDAX) was used.

Computational details. First-principles calculations were performed with experimental crystal structures using density functional theory (DFT) as implemented in the SIESTA package.⁴²⁻⁴³ Calculations have been carried out on experimental structures with the GGA functional in the PBE form.⁴⁴ Core electrons were described with Troullier-Martins pseudopotentials,⁴⁵ while valence wavefunctions were developed over double- ζ polarized basis set of finite-range numerical pseudoatomic orbitals.⁴⁶ Spin-orbit coupling was taken into account through the on-site approximation as proposed by Fernández-Seivane *et al.*⁴⁷ In all cases, an energy cutoff of 150 Ry for real-space mesh size was used.

RESULTS AND DISCUSSION

All presented compounds were crystallized from hydrobromic acid (HBr, 48 % water solution) under Argon atmosphere using Sn powder, CsBr, and G_2CO_3 as precursors. G_2SnBr_4 (**I**), obtained from stoichiometric quantities of G and Sn(II), crystallizes as colorless transparent needles. Compound **I** was then characterized by single-crystal XRD (Figures 1a, b, S2, Table S1-S4) and found to crystallize in the orthorhombic crystal system, space group $Pna2_1$. This structure consists of corrugated chains oriented along [010] (*i.e.*, extended in b direction), comprising corner-sharing square pyramids - $[SnBr_5]^{2-}$. The formation of such pyramids emphasizes the stereoactivity of the lone pair of Sn(II). The G cations are situated in the space between the chains and connect them via hydrogen-halogen bonds into a 3D supramolecular structure (Table S2). Two non-equivalent pyramids can be identified, which connect in an alternating manner. In both kinds of pyramids, Sn atoms are displaced out of the basal planes (by 0.23 and 0.24 Å, for Br1Br2Br5Br4 and Br2Br5Br8Br7 planes, respectively, Figure 1b). The Sn-Br bond lengths are in the range of 2.724(2)–3.117 Å, which is comparable to the

distances found in $(NH_4)SnBr_3 \cdot H_2O$ (2.623–3.047 Å), where Sn(II) has the same square-pyramidal coordination.⁴⁸ The shortest Sn-Br bond is with the Br ion at the apex of the pyramid. G_2SnBr_4 (**I**) has a similar crystal structure as G_2PbBr_4 , which contains an alternating orientation of $[PbBr_5]^{2-}$ square pyramids in 1D chains.⁴⁹ The 1D character is confirmed by inspection of the DFT electronic structure (Figure 2). Indeed, the band diagram (Figure 2a) exhibits an indirect bandgap of 3.12 eV, and no dispersion of the edge state bands is observed except when following a path corresponding to the [010] crystal direction. Furthermore, the computed electronic edge state densities exhibit sizeable overlaps, but only along the b crystallographic direction (Figure 2b) thus confirming the 1D character of the density of states close to the bandgap. It is also worth noticing that a Rashba splitting of the band edge states is observed both in the conduction and valence bands away from the Y, R and T critical points of the Brillouin zone as a result of the polar space group $Pna2_1$ assigned to (**I**). Sn-I square pyramidal units were also observed when using larger cations, such as $[C_3H_7N(C_2H_4)_3NC_3H_7]^{2+}$.¹⁹ G_2SnBr_4 (**I**) is thermally stable up to at least 300 °C (see TGA/DSC analysis in Figure S3). Two endothermic processes without mass loss occur before the decomposition at around 146 and 190 °C and indicate melting and/or other structural transitions.

Studies on a ternary 3D phase – the black $CsSnBr_3$ – date back to as early as the 1970s. $CsSnBr_3$ crystallizes in a cubic perovskite crystal structure (space group $Pm-3m$, Figure 3a) and melts congruently at 450 °C.⁵⁰⁻⁵² A phase transition to a tetragonally distorted lattice appears upon cooling to below 19 °C.⁵² The yellow $CsSnI_3$ crystallizes in the orthorhombic crystal system. $CsSnI_3$ is a 1D compound composed of edge-sharing $[SnI_6]^{-1}$ octahedra,⁵³ and converts into a cubic 3D phase only at 152 °C.⁵² Similarly, $CsPbI_3$ is known to crystallize in a 3D-lattice (cubic, space group $Pm-3m$) at higher temperatures and

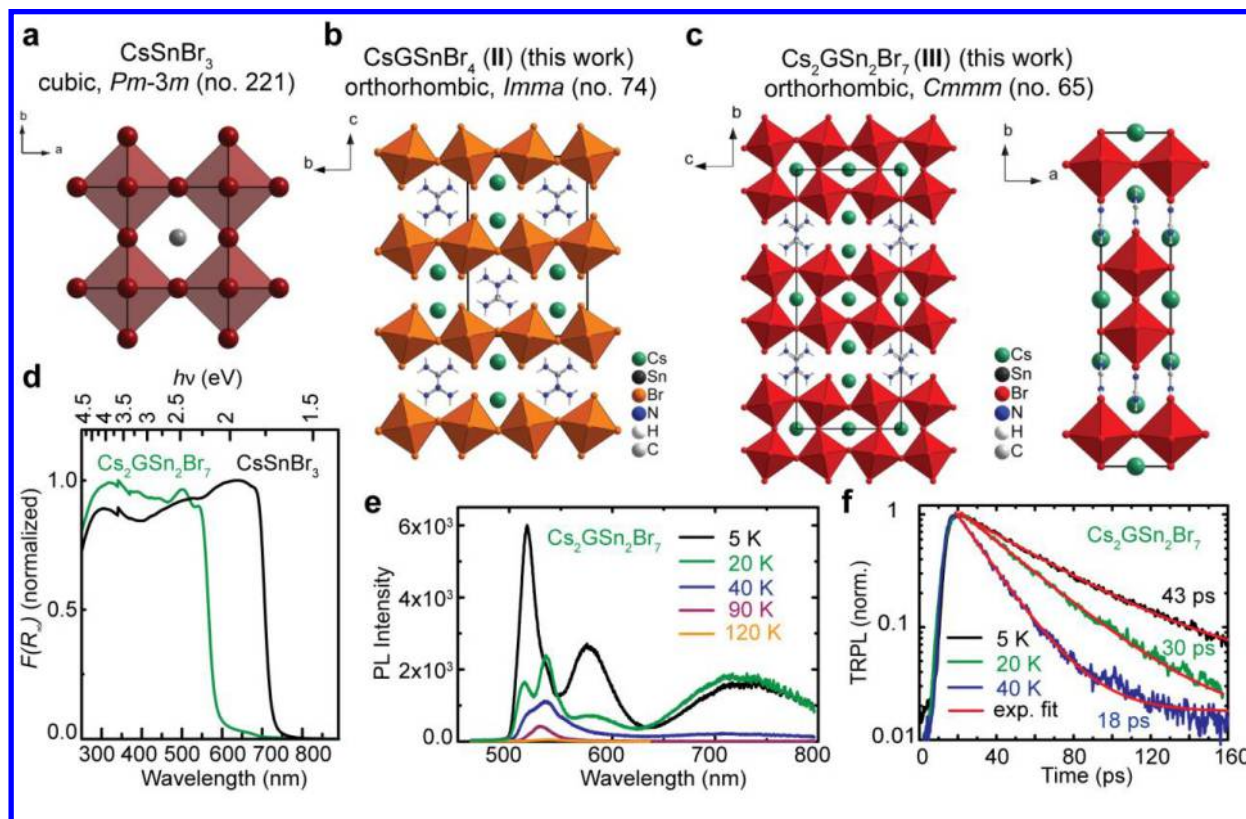


Figure 3. (a) Crystal structure of cubic 3D-perovskite CsSnBr_3 . (b, c) Crystal structure of two-dimensional perovskites: CsGSnBr_4 (**II**) and $\text{Cs}_2\text{GSn}_2\text{Br}_7$ (**III**). (d) Kubelka–Munk function of CsSnBr_3 and **III** at RT. (e) Selected low-temperature PL spectra of **III**. (f) Selected low-temperature time-resolved PL spectra of **III**.

converts into 1D-phase, analogous to 1D- CsSnI_3 , within the 329 – 290 °C temperature range.⁵⁴

We were then interested to see the effect of Br-I mixing in the Cs-Sn-X system. Interestingly, the addition of iodide with $[\text{I}]/[\text{Sn}] = 19/1$ (in concentrated HBr) leads to the precipitation of $\text{Cs}_8\text{Sn}_6\text{Br}_{13}\text{I}_7$ in the form of orange needles. It crystallizes in the orthorhombic crystal system, space group $Cmcm$ (Tables S5–S7) and consists of layers of corner (through $\mu_2\text{-Br}$) and edge-sharing (through $\mu_3\text{-I}$ ions) distorted $[\text{SnBr}_4\text{I}_2]^{-1\frac{1}{2}}$ and $[\text{SnBr}_3\text{I}_3]^{-1\frac{1}{2}}$ octahedra (Figure S4a, b). Iodide has one full and two partially occupied positions that are shared with bromide ions. The Cs^+ cations are situated in-between, as well as within, Sn(II) halide layers. There are two types of crystallographic surroundings for the Sn(II) ions; one characterized by the presence of a very weak Sn-I bond of 3.723 Å – in $[\text{SnBr}_3\text{I}_3]^{-1\frac{1}{2}}$ octahedra (see Sn1 atom in Figure S4b). The Sn2-I1 distances within $[\text{SnBr}_4\text{I}_2]^{-1\frac{1}{2}}$ are 3.454 Å, which is in the range of $d(\text{Sn-I})$ in CsSnI_3 , 2.942 – 3.470 Å.⁵³ Based on powder XRD analysis, $\text{Cs}_8\text{Sn}_6\text{Br}_{13}\text{I}_7$ was obtained as a pure phase (Figure S4c) with a homogeneous composition that was estimated with EDX (Figure S5a–c). The same structural motif was found in $\text{Cs}_{2.38}\text{Rb}_{1.62}\text{Sn}_3\text{Cl}_8\text{I}_2$, recently reported by Li, *et al.*,⁵⁵ obtained by solid-state reaction. The optical band edge of $\text{Cs}_8\text{Sn}_6\text{Br}_{13}\text{I}_7$ lies at 2.23 eV (Figure S6a, b), which is 0.58 eV smaller than the optical bandgap of $\text{Cs}_{2.38}\text{Rb}_{1.62}\text{Sn}_3\text{Cl}_8\text{I}_2$.⁵⁵

By comparing the experimental powder XRD patterns with those simulated from single-crystal XRD data obtained herein (except for CsSnBr_3 , where ICSD card 4071 was used), **I** and CsSnBr_3 were determined to be phase-pure (Figure S7, S8). CsSnBr_3 also appears to contain amorphous CsSnBr_3 (Figure

S8), which can explain the partially-resolved component at 650–700 nm in the PL spectrum (Figure 1d). We then obtained two mixed guanidinium-cesium tin bromides: CsGSnBr_4 (**II**, orange colored) and $\text{Cs}_2\text{GSn}_2\text{Br}_7$ (**III**, red-colored), as a mixture of crystals. Both compounds are layered perovskites (Figure 3b, c). The formation of these phases was found to be in strong competition with the crystallization of compounds **I** and CsSnBr_3 . $\text{Cs}_2\text{GSn}_2\text{Br}_7$ (**III**) was obtained as the dominant phase, with CsGSnBr_4 (**II**) as a major impurity (below 10 %, Figure S9) at a molar ratio of $\text{Cs/G/Sn} = 1/6/1$. Optical absorption analysis of the sample of $\text{Cs}_2\text{GSn}_2\text{Br}_7$ by a Kubelka–Munk function points to a possible trace quantity of a rather amorphous CsSnBr_3 thus giving rise to a small shoulder in the 650–700 nm region (Figure 3d). Both **II** and **III** crystallize in the orthorhombic crystal system, namely in $Imma$ (**II**) and $Cmcm$ (**III**) space groups, respectively (Figure 3b, c, Table S1). The crystal structures of **II** and **III** consist of 2D perovskite layers of corner-sharing $[\text{SnBr}_6]^{4-}$ octahedra that are separated by cesium and guanidinium cations. The derivation of these structures can be visualized by cutting the parental cubic CsSnBr_3 perovskite lattice along the (100) crystallographic plane and adding the octahedral tilting (discussed later in detail). The importance of the mixed-cation design for obtaining 2D-perovskites had been previously reported for the analogous CsGpBr(I)_4 and Cs_2GpBr_7 compounds.⁴⁹ Compound **II** contains monolayers of corner-sharing octahedra (Figure 3b), whereas compound **III** features double layers, connected via corners (Figure 3c). To the best of our knowledge, this is the first tin bromide featuring multi-layers. The perovskite slabs are mutually shifted in-plane by a vector $a/2$ (a being an ideal cubic cell vector, Figure 3c). Cs^+ and G

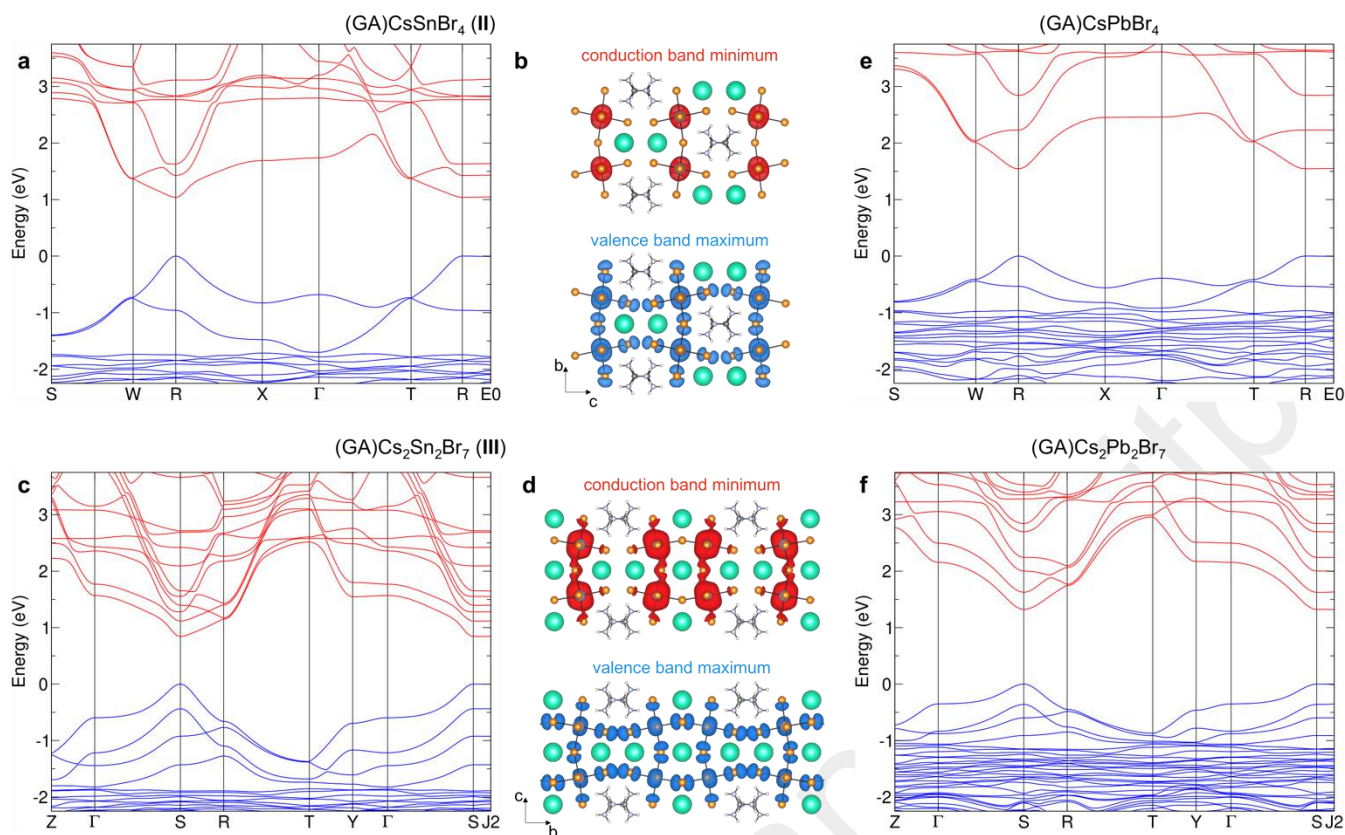


Figure 4. (a) Electronic band structure and (b) representation of the electronic densities of the conduction (red) and valence (blue) edge states (at the R point of the *Imma* Brillouin zone) of CsGSnBr₄ (**II**). R → E0 corresponds to the stacking direction. (b) and (d), same for Cs₂GSn₂Br₇ (**III**). S → J2 corresponds to the stacking direction. (e) Electronic band structures of CsGPbBr₄ and (f) Cs₂GPb₂Br₇. Electron densities are computed at the R point for **II** (b) and S point for **III** (d).

cations in **II** and **III** are both situated in the interlayer space, and alternate with each other in a periodic manner. In Cs₂GSn₂Br₇ (**III**), cesium cations also fill the voids within the perovskite layers. G forms hydrogen bonds with the bromide ions from the perovskite layers (Table S8, S9). G cations are closely packed with intermolecular d(C⋯N) distance of ca. 3 Å. Due to the difference in ionic radii of the Cs⁺ and G cations and the planar shape of the latter, Sn-Br octahedra are tilted in an alternating manner along the crystallographic axis *b* and *c* for **II** (Figure 3b) and **III** (Figure 3c left), respectively. This generates smaller cavities for Cs⁺ and large voids for G cations. However, in the in-plane direction (for instance along the crystallographic axis *a* for **III**, Figure 3c right) the planar shape of the G cation and small atomic radius of Cs⁺ lead to the absence of steric strain with almost perfectly collinear Sn and Br atoms and subsequently longer Sn-Sn distances (6.011 and 5.965 Å for **II** and **III**, respectively). This might contribute to an observed disorder in atomic positions of bromide along this direction. In CsGSnBr₄ (**II**), d(Sn-Br) = 2.909(2)-3.006(1) Å, are comparable to Sn-Br distances in a CsSnBr₃ cubic phase [d(Sn-Br) = 2.898 Å].⁵⁰ Sn-Br-Sn angles are in the range of 155.9(5)-180.0° (Figure S10). CsGSnBr₄ and CsGPbBr₄ both crystallize in the space group *Imma*, and are isotopic.⁴⁹ **III** is isotopic to Cs₂GPb₂Br₇, and crystallizes in the space group *Cmmm*.⁴⁹ The average Sn-Br distances for **III** are in the range of 2.915-2.987(1) Å (for additional crystallographic data for **II** and **III**, see Tables S10-S13). The interlayer Br⋯Br distances along the stacking direction (*c* and *b* for **II** and **III**, respectively) are rather short: d(Br⋯Br) = 4.161 Å in CsGPbBr₄ (**II**) and d(Br⋯Br) = 4.070 Å in Cs₂GSn₂Br₇ (**III**).

In 3D perovskites, the critical point of the Brillouin zone where a direct bandgap is observed is either the R-point,⁵⁶ for the cubic *Pm-3m* phase, or the Z-point for the distorted tetragonal *P4/mbm* phase (Figure S11). In both cases, the critical wavevectors have the point symmetries of their respective lattices (*m-3m* and *4/mmm*). Similar symmetry considerations lead to critical wavevectors located along the stacking directions at the X (0,0,1) and Y (0,1,0) high-symmetry points for **II** and **III**, respectively, in the *Imma* and *Cmmm* Brillouin zones (both with point groups *mmm*). However, DFT simulations (Figure 4a and c) show that the electronic bandgaps are predicted to be direct at the R (0.5,0,0.5) and S (0.5,0.5,0) points of the Brillouin zones of **II** and **III**, respectively. In both cases, the point symmetry of the critical wavevector is reduced from *mmm* to *2/m*. This can be related to the anisotropy of the out-of-plane octahedral tilts, which is directly induced by the shape of the G cations. The octahedral tilting is clearly apparent only in the (*b,c*) crystallographic planes (Figure 3-b and c). The difference between **II** and **III** lies in the fact that the (*b,c*) plane contains the stacking axis along *c* for **II** and along *b* for **III**. Furthermore, due to lattice distortions, the periodicity of the electronic density is doubled along *b* (*c*) for **II** (**III**), in contrast to the *a* direction. In turn, the valence band maxima and the conduction band minima show different hybridizations along all three directions (Figure 4b, 4d, and Figure S12) as well as different band dispersions (Figure 4a and c). Both compounds **II** and **III** exhibit flat dispersions along the stacking axis despite the short Br-Br distances, a characteristic feature of 2D systems. Analogously to CsSnBr₃ (Figure S11) and contrary to **I** (Figure 2), the bandgap remains

direct in both **II** and **III** (Figure 4a and c) with a systematic decrease of the bandgap values with the decrease of dimensionality and thickness of perovskite layers. These variations in DFT bandgap energies (Table S14) are related to the equivalent quantum well thickness ($n = 1, 2$ or ∞), which is roughly doubled when going from CsGSnBr₄ (**II**) to Cs₂GSn₂Br₇ (**III**) as a result of quantum confinement.

To experimentally probe the energy bandgaps in these hybrid tin bromide compounds, an optical absorption analysis by means of a Kubelka-Munk function as well as PL measurements were performed (Figure 1c,d, 3d,e). The Kubelka-Munk absorption representation was derived from the diffuse reflectance spectra of powdered samples, and was estimated as $F(R_{\infty}) = \alpha/S = (1-R_{\infty})^2/2R_{\infty} [F(R_{\infty}) - \text{Kubelka-Munk units}, \alpha - \text{absorption coefficient}, S - \text{the scattering coefficient, and } R_{\infty} - \text{the reflectance of an infinitely thick layer}]$. Here we neglected the influence of excitonic effects on the absorption, because the excitonic band cannot be consistently resolved for all compounds and thus correctly de-convoluted from the bandgap absorption edge. Hence the bandgap can be slightly underestimated. The optical bandgap energies for **I**, **III** and CsSnBr₃ were determined by plotting $[F(R_{\infty}) \cdot h\nu]^r$ versus $(h\nu)$ ($h\nu$ - the incident photon energy, $r = 2$ for direct bandgap semiconductor, and $r = 1/2$ for indirect bandgap semiconductor; Figure S13a,b). The highest absorption edge energy (ca. 3.11 eV) was found for G₂SnBr₄ (**I**) (Figure 1c), which is in agreement with its lowest electronic dimensionality (1D). The 3D cubic CsSnBr₃ has the smallest bandgap energy (1.74 eV, in agreement with literature⁵⁷), whereas the 2D Cs₂GSn₂Br₇ (**III**) has an intermediate bandgap value of 2.16 eV (Figure 3d). Compound **II** could not be obtained in the phase-pure form needed for diffuse reflectance (only individual small crystallites could be selected for a single-crystal XRD analysis). However, the visual appearance of **II** pointed towards an expected higher bandgap in comparison to **III** (orange vs. red). Despite the well-known underestimation of bandgaps, such a decrease is predicted from DFT calculations (Figure 4 and Table S14) with 1.04 eV for **II** and 0.84 eV **III**. Cs₂G₂Pb₂Br₇ has a larger optical experimental bandgap than **III**, by 0.44 eV (2.60 eV vs. 2.16 eV).⁴⁹ A similar scenario was observed for the pair of (C₆H₉C₂H₄NH₃)₂SnBr₄ (2.5 eV optical bandgap) and its lead analog (2.9 eV).⁵⁸ This might be a result of the difference in the E₃ ionization energies between tin and lead [E₃(Pb) = 31.94 eV and E₃(Sn) = 30.5 eV], the effect of the additional polarizability (presence of filled diffuse *d* and *f* orbitals below the valence electrons in Pb), and the distortions of the M-X (M = Sn, Pb) octahedra. A different degree of tilting of the MBr₆ octahedra is observed for Cs₂G₂Pb₂Br₇ and **III** (Figure S14), with stronger deviations from the ideal 180° for the lead compound. Interestingly, despite the different tilts of the octahedra, the angles are at the end compensated in a manner that gives the required amount of space for guanidinium and cesium cations. Figure 4e and f report the computed band structures for the lead-based analogs of compounds **II** and **III** that share many similarities with the tin-based layered perovskites (Figure 4a and c). Both for **II** and **III**, the predicted electronic bandgaps follow the same trends as the above mentioned experimental results. For instance, the bandgap increases from 1.04 eV (Sn) to 1.55 eV (Pb) for **II** and from 0.84 eV (Sn) to 1.32 eV (Pb) for **III**.

Both CsSnBr₃ and **I** are luminescent at RT, unlike **II** and **III**. The PL of G₂SnBr₄ (**I**) at RT is characterized by a broad emission

band (Figure 1d) with a FWHM of ca. 121 nm, 2 % PLQY, and a large Stokes shift of ca. 208 nm. At 77 K, the PLQY reaches 75±5 % and the PL band narrows (FWHM ~72 nm) while retaining the same peak position at 557 nm with a Stokes shift of 233 nm. Additionally, the PL excitation spectrum at 77 K is blue-shifted compared to that at RT. CsSnBr₃ exhibits a PL maximum at 1.70 eV (Figure 1d) at RT, which is consistent with the literature value.⁵⁷ In the PL spectrum of CsSnBr₃, a shoulder was observed at the higher energy side, which seems to originate from an amorphous or nanocrystalline CsSnBr₃ impurity.⁵⁹ A blue shift of the emission bands of CsSnBr₃ was observed when the temperature increased from 228 to 383 K (Figure S15). This trend is consistent with previous temperature-dependent PL theoretical and experimental studies and is explained by the lattice expansion upon heating and local displacements of the Sn(II) cation.^{57, 60-61} Large differences in the width of the PL bands and Stokes shifts for G₂SnBr₄ (**I**) and CsSnBr₃ indicate different radiative processes in these compounds. Time-resolved PL measurements (Figure 1e) yielded a PL lifetime of 0.4 ns for CsSnBr₃ and 18 ns in compound **I**. The short lifetime, the small Stokes shift and the narrow PL band attest to the excitonic nature of the radiative transition in CsSnBr₃. On the contrary, the longer PL lifetime and larger Stokes shift and broader FWHM point to emission via self-trapped excitons in compound **I** (Figure 1f). Importantly, the PL lifetime in 1D G₂SnBr₄ is much faster (18 ns) than that commonly found in 0D Sn(II)-halides (10²-10³ ns for bromide) at RT.^{6-8, 28} This might eventually lead to a practical advantage, for instance, in the context of applications such as white-light sources,^{7-8, 27} as the achievable saturated emission brightness scales with the PL lifetime.

For **II** and **III**, which are structurally more rigid and exhibit a delocalized electronic structure that reduces the propensity to form self-trapped excitons, the PL was measurable only at cryogenic temperatures (5 K - 120 K, Figure 3e). At 5 K, the main band peaks at 517 nm with an additional emission band around 577 nm. A broad emission band above 700 nm is also visible. Due to the very low PLQY and presence of different phases within the same sample, it is difficult to draw solid conclusions. Yet one can attribute the main emission bands to free excitons or self-trapped excitons with low stabilization energy (due to hindered structural distortion as compared to 0D and 1D-compounds). Finally, the lowest energy band might stem from surface defects. By increasing the temperature, the PL intensity quickly drops due to the activation of non-radiative processes. We have performed time-resolved PL measurements with a streak camera system, and the results are displayed in Figure 3f. The measured sub-100-ps decay times and their dependence on temperature attest to the presence of non-radiative processes, which efficiently quench radiative recombination.

In conclusion, we presented a highly luminescent at 77 K 1D-compound G₂SnBr₄, as well as layered 2D-perovskites CsGSnBr₄ and Cs₂GSn₂Br₇. In G₂SnBr₄, the Sn(II) lone pair is stereoactive and influences the coordination environment of Sn(II). G₂SnBr₄ is a luminescent compound with broadband emission from self-trapped excitonic states that are enabled by the soft-lattice and electronic localization. This emission is characterized by PL QY of 2 % at RT and 75±5 % at 77 K. G₂SnBr₄ does not thermally decompose until 300 °C. The addition of cesium to the G-Sn-Br system promotes the formation of structurally more rigid, layered perovskite compounds, obscuring the formation of self-trapped excitons

but leading to a delocalized electronic structure. $\text{Cs}_2\text{GSn}_2\text{Br}_7$ has a smaller bandgap than its lead analog, $\text{Cs}_2\text{GPb}_2\text{Br}_7$, due to the difference in E_3 ionization energies of tin and lead, higher electronegativity of Pb, as well as the different degree of structural distortion. Lastly, in-plane electronic coupling is anisotropic as a result of the planar shape of the guanidinium cation, which leads to significant octahedral out-of-plane tilting in only one of the two directions.

ASSOCIATED CONTENT

Supporting Information

The Supporting Information is available free of charge on the ACS Publications website. The Supporting information contains additional data on single crystal and powder XRD, thermal analysis, optical characterization, as well as EDX spectroscopy and electronic structure calculations.

AUTHOR INFORMATION

Corresponding Author

*mvkovalenko@ethz.ch

Notes

The authors declare no competing financial interests.

ACKNOWLEDGMENT

Authors thank IBM-Zurich Research, in particular Dr. T. Stöferle and Dr. R.F. Mahrt, for support with low-temperature PL experiments. This work was financially supported by the European Union through the FP7 (ERC Starting Grant NANOSOLID, GA No. 306733). DFT calculations were performed at the Institut des Sciences Chimiques de Rennes, which received funding from Agence Nationale pour la Recherche (TRANSHYPERO project) and the work was granted access to the HPC resources of TGCC/CINES/IDRIS under the allocation 2018-A0030907682 made by GENCI. J.E. is a senior member of Institut Universitaire de France. The work at Institut FOTON was supported by Agence Nationale pour la Recherche (SupersansPlomb project).

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